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View Online at https://aerobasegroup.com/nsn/5961-01-315-4418

Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.295 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-450.0 collector to base voltage/static/emitter open and -6.0 emitter to base voltage, static, collector open and -450.0 collector to emitter

voltage, dc with specified circuit between base and emitter

Current Rating Per Characteristic:

-2.00 amperes source cutoff current and -1.00 amperes source cutoff current

Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 pin and 1 case

Specification Data:

80131-release 6426 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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